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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/734,749	12/11/2003	Haoren Zhuang	14580-045001 / FP2078	9525
20985	7590	09/15/2006	EXAMINER	
FISH & RICHARDSON, PC P.O. BOX 1022 MINNEAPOLIS, MN 55440-1022			CHACKO DAVIS, DABORAH	
			ART UNIT	PAPER NUMBER
			1756	

DATE MAILED: 09/15/2006

Please find below and/or attached an Office communication concerning this application or proceeding.

Office Action Summary	Application No.	Applicant(s)
	10/734,749	ZHUANG, HAOREN
	Examiner	Art Unit
	Daborah Chacko-Davis	1756

-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --
Period for Reply

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) OR THIRTY (30) DAYS, WHICHEVER IS LONGER, FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

Status

1) Responsive to communication(s) filed on 10 July 2006.
 2a) This action is FINAL. 2b) This action is non-final.
 3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

Disposition of Claims

4) Claim(s) 1-7 and 12-17 is/are pending in the application.
 4a) Of the above claim(s) _____ is/are withdrawn from consideration.
 5) Claim(s) _____ is/are allowed.
 6) Claim(s) 1-7, 12-17 is/are rejected.
 7) Claim(s) _____ is/are objected to.
 8) Claim(s) _____ are subject to restriction and/or election requirement.

Application Papers

9) The specification is objected to by the Examiner.
 10) The drawing(s) filed on _____ is/are: a) accepted or b) objected to by the Examiner.
 Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).
 Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).
 11) The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.

Priority under 35 U.S.C. § 119

12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
 a) All b) Some * c) None of:
 1. Certified copies of the priority documents have been received.
 2. Certified copies of the priority documents have been received in Application No. _____.
 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).

* See the attached detailed Office action for a list of the certified copies not received.

Attachment(s)

1) Notice of References Cited (PTO-892)
 2) Notice of Draftsperson's Patent Drawing Review (PTO-948)
 3) Information Disclosure Statement(s) (PTO/SB/08)
 Paper No(s)/Mail Date _____.

4) Interview Summary (PTO-413)
 Paper No(s)/Mail Date. _____.
 5) Notice of Informal Patent Application
 6) Other: _____.

DETAILED ACTION

Claim Rejections - 35 USC § 102

1. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless –

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

2. Claims 1-3, 5-7, 12, 14-17, are rejected under 35 U.S.C. 102(b) as being anticipated by U. S. Patent No. 6,051,858 (Uchida et al., hereinafter referred to as Uchida).

Uchida, in the abstract, in col 2, lines 33-38, col 14, lines 46-67, in col 15, lines 1-48, in col 22, lines 34-64, discloses a method of forming a patterned hard mask on a ferroelectric capacitor includes forming a photosensitive solution of a sol-gel layer (metal precursor complex) on the capacitor device (ferroelectric capacitor), forming a pattern on the sol-gel layer, and developing the exposed sol-gel layer (etching or removing in an etchant the non-exposed part of the precursor layer to form the negative pattern, patterning the sol-gel layer photolithographically) heating the patterned sol-gel layer (patterned liquid coated precursor, patterned protective layer) in a nitrogen atmosphere to form a metal nitride mask pattern (titanium nitride mask) (claims 1-2, 12). Uchida, in col 14, lines 46-67, in col 15, lines 1-48, discloses that the sol-gel layer includes a titanium organic sol gel layer (metal-organic complex layer or metal alkoxide in an organic precursor), wherein the organic group is an ethyl acac, the metal includes

titanium or metal alkoxides (claims 3, and 5-7). Uchida, in col 18, lines 50-56, discloses that the sol-gel layer is spin coated onto the device (claim 14). Uchida, in col 7, lines in col 13, lines 40-46, and in col 14, lines 24-56, discloses that the patterned mask (protective layer mask, hard mask) is used to ion mill the device beneath, and that the device is a FeRAM capacitor (claims 15-17).

Claim Rejections - 35 USC § 103

3. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.

4. Claims 4, and 13, are rejected under 35 U.S.C. 103(a) as being unpatentable over U. S. Patent No. 6,051,858 (Uchida et al., hereinafter referred to as Uchida) in view of U. S. Patent Application Publication No. 2004/0164293 (Maloney et al., hereinafter referred to as Maloney).

Uchida is discussed in paragraph no. 2.

The difference between the claims and Uchida is that Uchida does not disclose that the photosensitive sol-gel layer is a titanium-aluminum organic sol-gel layer (claim 4). Uchida does not disclose that the converted patterned protective nitride layer includes Ti-Al as the metallic part of the metallic nitride material (claim 13).

Maloney, in [0107], [0144], [0145], [0146], [0147], discloses that the hard mask layer is a photosensitive sol-gel layer comprising a metal complex precursor of the claimed composition (including plural metallic (Ti-Al) organic precursor compositions).

Therefore, it would be obvious to a skilled artisan to modify Uchida by employing the photosensitive sol-gel composition suggested by Maloney because Maloney, in [0173], discloses that employing the photosensitive (metal precursor) sol-gel layer as the hard mask layer enables low temperature processing and a four-fold reduction in carbon residues.

Response to Arguments

5. Applicant's arguments with respect to claims 1-7, and 12-17, filed July 10, 2006, have been considered but are moot in view of the new ground(s) of rejection. See paragraph nos. 2, and 4.

Conclusion

6. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Daborah Chacko-Davis whose telephone number is (571) 272-1380. The examiner can normally be reached on M-F 9:30 - 6:00. If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Mark F Huff can be reached on (571) 272-1385. The fax phone number for the organization where this application or proceeding is assigned is (571) 273-8300. Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published

applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see <http://pair-direct.uspto.gov>. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

dcd

September 12, 2006.



JOHN A. MCPHERSON
PRIMARY EXAMINER